DESCRIPTION
The ZXCT1009 is a high side current sense monitor. Using this device eliminates the need to disrupt the ground plane when sensing a load current.

It takes a high side voltage developed across a current shunt resistor and translates it into a proportional output current.

A user defined output resistor scales the output current into a ground-referenced voltage.

The wide input voltage range of 20V down to as low as 2.5V make it suitable for a range of applications. A minimum operating current of just 4µA, combined with its SOT23 package make it a unique solution for portable battery equipment.

FEATURES
• Low cost, accurate high-side current sensing
• Output voltage scaling
• Up to 2.5V sense voltage
• 2.5V – 20V supply range
• 4µA quiescent current
• 1% typical accuracy
• SOT23 and SM8 packages

APPLICATIONS
• Battery chargers
• Smart battery packs
• DC motor control
• Over current monitor
• Power management
• Level translating
• Programmable current source

APPLICATION CIRCUIT

ORDERING INFORMATION

<table>
<thead>
<tr>
<th>DEVICE</th>
<th>REEL SIZE</th>
<th>TAPE WIDTH</th>
<th>QUANTITY PER REEL</th>
<th>PARTMARKING</th>
<th>PACKAGE</th>
</tr>
</thead>
<tbody>
<tr>
<td>ZXCT1009FTA</td>
<td>7&quot;</td>
<td>8mm</td>
<td>3,000 units</td>
<td>109</td>
<td>SOT23</td>
</tr>
<tr>
<td>ZXCT1009T8TA</td>
<td>7&quot;</td>
<td>12mm</td>
<td>1,000 units</td>
<td>ZXCT1009</td>
<td>SM8</td>
</tr>
</tbody>
</table>
ABSOLUTE MAXIMUM RATINGS

Voltage on any pin: -0.6V to 20V (relative to \( I_{\text{out}} \))
Continuous output current: 25mA
Continuous sense voltage: \( V_{\text{in}} + 0.5V > V_{\text{sense}} \) > \( V_{\text{in}} - 5V \)
Operating temperature: -40 to 85°C
Storage temperature: -55 to 125°C
Package power dissipation (\( T_A = 25°C \)): SOT23 450mW - derate to zero at 125°C
SM8 2W

Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings for extended periods may reduce device reliability.

ELECTRICAL CHARACTERISTICS

Test Conditions \( T_A = 25°C \), \( V_{\text{in}} = 5V \), \( R_{\text{out}} = 100\Omega \).

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>LIMITS</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>( V_{\text{in}} )</td>
<td>( V_{\text{CC}} ) range</td>
<td></td>
<td>Min</td>
<td>Typ</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>2.5</td>
<td></td>
</tr>
<tr>
<td>( I_{\text{out}}^1 )</td>
<td>Output current</td>
<td>( V_{\text{sense}} = 0V )</td>
<td>1</td>
<td>4</td>
</tr>
<tr>
<td></td>
<td></td>
<td>( V_{\text{sense}} = 10mV )</td>
<td>90</td>
<td>104</td>
</tr>
<tr>
<td></td>
<td></td>
<td>( V_{\text{sense}} = 100mV )</td>
<td>0.975</td>
<td>1.002</td>
</tr>
<tr>
<td></td>
<td></td>
<td>( V_{\text{sense}} = 200mV )</td>
<td>1.95</td>
<td>2.0</td>
</tr>
<tr>
<td></td>
<td></td>
<td>( V_{\text{sense}} = 1V )</td>
<td>9.6</td>
<td>9.98</td>
</tr>
<tr>
<td>( V_{\text{sense}}^1 )</td>
<td>Sense voltage</td>
<td></td>
<td>0</td>
<td>2500</td>
</tr>
<tr>
<td>( I_{\text{sense}} )</td>
<td>Input current</td>
<td>( V_{\text{sense}} )</td>
<td></td>
<td>100</td>
</tr>
<tr>
<td>Acc</td>
<td>Accuracy</td>
<td>( R_{\text{sense}} = 0.1\Omega )</td>
<td>-2.5</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>( V_{\text{sense}} = 200mV )</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Gm</td>
<td>Transconductance, ( \frac{I_{\text{out}}}{V_{\text{sense}}} )</td>
<td></td>
<td>10000</td>
<td></td>
</tr>
<tr>
<td>BW</td>
<td>Bandwidth</td>
<td>RF ( P_{\text{in}} = -20dBm )</td>
<td>300</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>( V_{\text{sense}} = 10mV ) dc</td>
<td>2</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>( V_{\text{sense}} = 100mV ) dc</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

\(^1\) Includes input offset voltage contribution
\(^1\) \( V_{\text{sense}} = V_{\text{in}} - V_{\text{load}} \)
\(^1\) -20dBm=63mVp-p into 50Ω
TYPICAL CHARACTERISTICS

- **Typical Output v Sense Voltage**
- **Error v Sense Voltage**
- **Output Current v Temperature**
- **Frequency Response**
- **Transfer Characteristic**
- **Common Mode Rejection**

**Notes:**
- **V_{IN} = 5V**
- **T_{amb} = 25°C**
- **R_{OUT} = 0Ω**

**Parameters:**
- **Output Current (A)**
- **Gain (dB)**
- **Frequency (MHz)**
- **Supply Voltage (V)**
- **Frequency (Hz)**
- **Rejection (dB)**

**Specifications:**
- ** typical operating conditions**
- **maximum operating conditions**
**PIN DESCRIPTION**

<table>
<thead>
<tr>
<th>Pin Name</th>
<th>Pin Function</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{sense-}$</td>
<td>Supply voltage</td>
</tr>
<tr>
<td>$V_{sense+}$</td>
<td>Connection to load/battery</td>
</tr>
<tr>
<td>$I_{out}$</td>
<td>Output current, proportional to $V_{in}$-$V_{load}$</td>
</tr>
</tbody>
</table>

**CONNECTION DIAGRAMS**

**SOT23**
- Package Suffix: F
- Top View

**SM8**
- Package Suffix: T8
- Top View

**TYPICAL CHARACTERISTICS (Cont.)**

- Step Response
- Voltage (V)
  - $V_{in}$
  - $V_{sense+}$
  - $V_{sense-}$
- Current (A)
  - $I_{out}$
- Time (μs)
  - 0 to 20

**SCHEMATIC DIAGRAM**

- $V_{sense+}$
- $V_{sense-}$
- $100\Omega$
- $I_{out}$
POWER DISSIPATION

The maximum allowable power dissipation of the device for normal operation (P_{max}), is a function of the package junction to ambient thermal resistance (\( \theta_{ja} \)), maximum junction temperature (T_{jmax}), and ambient temperature (T_{amb}), according to the expression:

\[ P_{max} = \frac{T_{jmax} - T_{amb}}{\theta_{ja}} \]

The device power dissipation, P_D, is given by the expression:

\[ P_D = I_{out} (V_{in} - V_{out}) \text{ Watts} \]

APPLICATIONS INFORMATION

The following lines describe how to scale a load current to an output voltage.

\[ V_{sense} = V_{in} - V_{load} \]

\[ V_{out} = 0.01 \times V_{sense} \times R_{out} \]

E.g.

A 1A current is to be represented by a 100mV output voltage:

1) Choose the value of R_{sense} to give 50mV > V_{sense} > 500mV at full load.

For example V_{sense} = 100mV at 1.0A. R_{sense} = 0.1/1.0 = 0.1 ohms.

2) Choose R_{out} to give V_{out} = 100mV, when V_{sense} = 100mV.

Rearranging for R_{out} gives:

\[ R_{out} = \frac{V_{out}}{V_{sense} \times 0.01} \]

\[ R_{out} = \frac{0.1}{0.1 \times 0.01} = 100 \Omega \]

TYPICAL CIRCUIT APPLICATION

Where R_{load} represents any load including DC motors, a charging battery or further circuitry that requires monitoring, R_{sense} can be selected on specific requirements of accuracy, size and power rating.
Li-Ion Charger Circuit

The above figure shows the ZXCT1009 supporting the Benchmark bq2954 Charge Management IC. Most of the support components for the bq2954 are omitted for clarity. This design also uses the Zetex FZT789A high current Super-B PNP as the switching transistor in the DC-DC step down converter and the FMMT451 as the drive NPN for the FZT789A. The circuit can be configured to charge up to four Li-Ion cells at a charge current of 1.25A. Charge can be terminated on maximum voltage, selectable minimum current, or maximum time out. Switching frequency of the PWM loop is approximately 120kHz.

The ZXCT1009 is intended as a direct functional replacement for the ZDS1009, which is featured in a complete design from Unitrode/Texas Instruments on the Li-Ion charger circuit shown above. Reference: DVS2954S1H Li-Ion Charger Development System.

Transient Protection

An additional resistor, R\text{l}\text{im} can be added in series with Rout (figure 1.0), to limit the current from I\text{o}\text{ut}. Any circuit connected to V\text{o}\text{ut} will be protected from input voltage transients. This can be of particular use in automotive applications where load dump and other common transients need to be considered.

![Figure 1.0: ZXCT1009 with additional current limiting Resistor R\text{l}\text{im}](image)

Assuming the worst case condition of V\text{o}\text{ut} = 0V; providing a low impedance to a transient, the minimum value of R\text{l}\text{im} is given by:-

\[
R\text{l}\text{im}(\text{min}) = \frac{V\text{pk} - V\text{max}}{I\text{pk}}
\]

where:
- \(V\text{pk}\) = Peak transient voltage to be withstood
- \(V\text{max}\) = Maximum working Voltage = 20V
- \(I\text{pk}\) = Peak output current = 40mA

The maximum value of R\text{l}\text{im} is set by V\text{i}\text{n}(\text{min}), V\text{o}\text{ut}(\text{max}) and the dropout voltage (see transfer characteristic on page 3) of the ZXCT1009:

\[
R\text{l}\text{im}(\text{max}) = \frac{R\text{out}[V\text{i}\text{n}(\text{min}) - (V\text{dp} + V\text{o}\text{ut}(\text{max}))]}{V\text{o}\text{ut}(\text{max})}
\]

where:
- \(V\text{i}\text{n}(\text{min})\) = Minimum Supply Operating Voltage
- \(V\text{dp}\) = Dropout Voltage
- \(V\text{o}\text{ut}(\text{max})\) = Maximum Operating Output Voltage
**PCB trace shunt resistor for low cost solution**

The figure below shows output characteristics of the device when using a PCB resistive trace for a low cost solution in replacement for a conventional shunt resistor. The graph shows the linear rise in voltage across the resistor due to the PTC of the material and demonstrates how this rise in resistance value over temperature compensates for the NTC of the device.

The figure opposite shows a PCB layout suggestion. The resistor section is 25mm x 0.25mm giving approximately 150mΩ using 1oz copper. The data for the normalised graph was obtained using a 1A load current and a 100Ω output resistor. An electronic version of the PCB layout is available at [www.zetex.com/isense](http://www.zetex.com/isense).

![](image)

**Effect of Sense Resistor Material on Temperature Performance**
PACKAGE DIMENSIONS SOT23

<table>
<thead>
<tr>
<th>DIM</th>
<th>Millimeters</th>
<th>Inches</th>
</tr>
</thead>
<tbody>
<tr>
<td>A</td>
<td>2.67 - 3.05</td>
<td>0.105 - 0.120</td>
</tr>
<tr>
<td>B</td>
<td>1.20 - 1.40</td>
<td>0.047 - 0.055</td>
</tr>
<tr>
<td>C</td>
<td>- 1.10</td>
<td>- 0.043</td>
</tr>
<tr>
<td>D</td>
<td>0.37 - 0.53</td>
<td>0.0145 - 0.021</td>
</tr>
<tr>
<td>F</td>
<td>0.085 - 0.15</td>
<td>0.0033 - 0.0059</td>
</tr>
<tr>
<td>G</td>
<td>NOM 1.9</td>
<td>NOM 0.075</td>
</tr>
<tr>
<td>K</td>
<td>0.01 - 0.10</td>
<td>0.0004 - 0.004</td>
</tr>
<tr>
<td>L</td>
<td>2.10 - 2.50</td>
<td>0.0825 - 0.0985</td>
</tr>
<tr>
<td>N</td>
<td>NOM 0.95</td>
<td>NOM 0.037</td>
</tr>
</tbody>
</table>

PACKAGE DIMENSIONS SM8

<table>
<thead>
<tr>
<th>DIM</th>
<th>Millimeters</th>
<th>Inches</th>
</tr>
</thead>
<tbody>
<tr>
<td>A</td>
<td>- - 1.7</td>
<td>- - 0.067</td>
</tr>
<tr>
<td>A1</td>
<td>0.02 - 0.1</td>
<td>0.0008 - 0.004</td>
</tr>
<tr>
<td>b</td>
<td>- 0.7</td>
<td>- 0.028</td>
</tr>
<tr>
<td>c</td>
<td>0.24 - 0.32</td>
<td>0.009 - 0.013</td>
</tr>
<tr>
<td>D</td>
<td>6.3 - 6.7</td>
<td>0.248 - 0.264</td>
</tr>
<tr>
<td>E</td>
<td>3.3 - 3.7</td>
<td>0.130 - 0.145</td>
</tr>
<tr>
<td>e1</td>
<td>- 4.59</td>
<td>- 0.180</td>
</tr>
<tr>
<td>e2</td>
<td>- 1.53</td>
<td>- 0.060</td>
</tr>
<tr>
<td>He</td>
<td>6.7 - 7.3</td>
<td>0.264 - 0.287</td>
</tr>
<tr>
<td>Lp</td>
<td>0.9 -</td>
<td>0.035 -</td>
</tr>
<tr>
<td>α</td>
<td>- - 15°</td>
<td>- - 15°</td>
</tr>
<tr>
<td>β</td>
<td>- 10°</td>
<td>- - 10°</td>
</tr>
</tbody>
</table>

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